

# ANTREX Electronics

Electronic Components Sourcing Information

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## Product Reference Information

**Part Number:** TLV5613IPW  
**Manufacturer:** Texas Instruments  
**Package:** 20-TSSOP (0.173&quot;, 4.40mm Width)  
**Availability:** Please confirm with sales

### Product Page:

<https://antrexco.com/product/details/texas-instruments/tlv5613ipw.html>

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### Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

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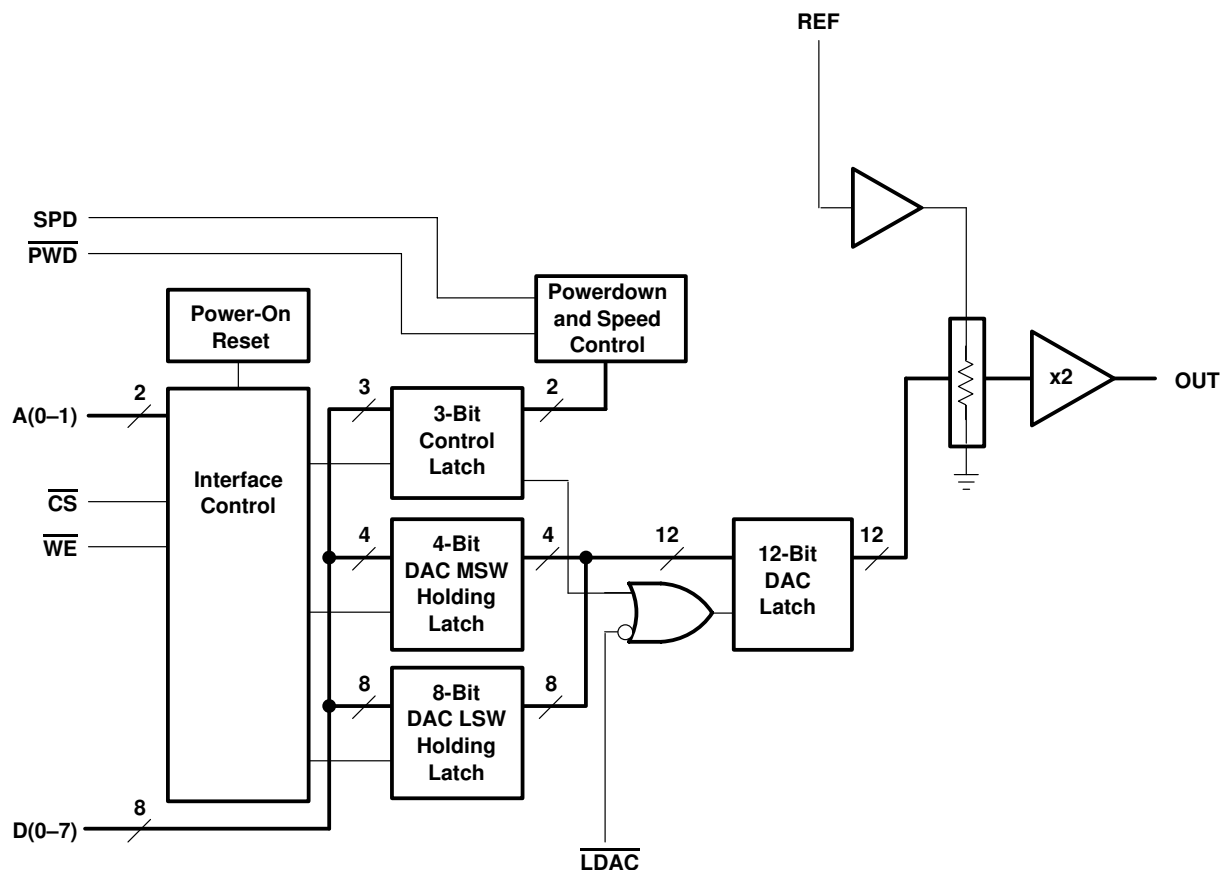
- Digital Servo Control Loops
- Battery Powered Test Instruments
- Digital Offset and Gain Adjustment
- Industrial Process Control
- Speech Synthesis
- Machine and Motion Control Devices
- Mass Storage Devices

# TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### functional block diagram



### Terminal Functions

| TERMINAL<br>NAME         | NO.         | I/O | DESCRIPTION                                                          |
|--------------------------|-------------|-----|----------------------------------------------------------------------|
| AV <sub>DD</sub>         | 11          |     | Analog positive power supply                                         |
| A0                       | 8           | I   | Address input                                                        |
| A1                       | 7           | I   | Address input                                                        |
| $\overline{\text{CS}}$   | 18          | I   | Chip select. Digital input active low, used to enable/disable inputs |
| DV <sub>DD</sub>         | 10          |     | Digital positive power supply                                        |
| D0 (LSB) – D7 (MSB)      | 1–6, 19, 20 | I   | Data input                                                           |
| $\overline{\text{LDAC}}$ | 16          | I   | Load DAC. Digital input active low, used to load DAC output          |
| OUT                      | 13          | O   | DAC analog voltage output                                            |
| $\overline{\text{PWD}}$  | 15          | I   | Power down. Digital input active low                                 |
| REF                      | 12          | I   | Analog reference voltage input                                       |
| SPD                      | 9           | I   | Speed select. Digital input                                          |
| GND                      | 14          |     | Ground                                                               |
| $\overline{\text{WE}}$   | 17          | I   | Write enable. Digital input active low, used to latch data           |

# TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

|                                                              |                              |
|--------------------------------------------------------------|------------------------------|
| Supply voltage ( $DV_{DD}$ , $AV_{DD}$ to GND)               | 7 V                          |
| Supply voltage difference, $AV_{DD}$ to $DV_{DD}$            | – 2.8 V to 2.8 V             |
| Reference input voltage range                                | – 0.3 V to $AV_{DD} + 0.3$ V |
| Digital input voltage range to GND                           | – 0.3 V to $DV_{DD} + 0.3$ V |
| Operating free-air temperature range, $T_A$ : TLV5613C       | 0°C to 70°C                  |
| TLV5613I                                                     | –40°C to 85°C                |
| Storage temperature range, $T_{stg}$                         | –65°C to 150°C               |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C                        |

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions

|                                                                |                            | MIN  | NOM   | MAX             | UNIT       |
|----------------------------------------------------------------|----------------------------|------|-------|-----------------|------------|
| Supply voltage, $V_{DD}$                                       | 5-V Supply                 | 4.5  | 5     | 5.5             | V          |
|                                                                | 3-V Supply                 | 2.7  | 3     | 3.3             |            |
| Supply voltage difference, $\Delta V_{DD} = AV_{DD} - DV_{DD}$ |                            | –2.8 | 0     | 2.8             | V          |
| Power on reset, POR                                            |                            | 0.55 |       | 2               | V          |
| High-level digital input voltage, $V_{IH}$                     | $DV_{DD} = 2.7$ V to 5.5 V | 2    |       |                 | V          |
| Low-level digital input voltage, $V_{IL}$                      | $DV_{DD} = 2.7$ V to 5.5 V |      |       | 0.8             | V          |
| Reference voltage, $V_{ref}$ to REFIN terminal                 | 5-V Supply (see Note 1)    | GND  | 2.048 | $AV_{DD} - 1.5$ | V          |
|                                                                | 3-V Supply (see Note 1)    | GND  | 1.024 | $AV_{DD} - 1.5$ |            |
| Load resistance, $R_L$                                         |                            | 2    |       |                 | k $\Omega$ |
| Load capacitance, $C_L$                                        |                            |      |       | 100             | pF         |
| Operating free-air temperature, $T_A$                          | TLV5613C                   | 0    |       | 70              | °C         |
|                                                                | TLV5613I                   | –40  |       | 85              | °C         |

NOTE 1: Due to the x2 output buffer, a reference input voltage  $\geq (V_{DD} - 0.4)/2$  causes clipping of the transfer function.

# 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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electrical characteristics over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

## power supply

| PARAMETER                 |                              | TEST CONDITIONS                                                         |                       |            | MIN | TYP  | MAX | UNIT |
|---------------------------|------------------------------|-------------------------------------------------------------------------|-----------------------|------------|-----|------|-----|------|
| I <sub>DD</sub>           | Power supply current         | No load,<br>All inputs = GND or DV <sub>DD</sub> ,<br>DAC latch = 0x800 | V <sub>DD</sub> = 5 V | Fast       |     | 1.6  | 3   | mA   |
|                           |                              |                                                                         |                       | Slow       |     | 0.5  | 1.3 | mA   |
|                           |                              |                                                                         | V <sub>DD</sub> = 3 V | Fast       |     | 1.4  | 2.7 | mA   |
|                           |                              |                                                                         |                       | Slow       |     | 0.4  | 1.1 | mA   |
| Power down supply current |                              | See Figure 14                                                           |                       |            |     | 0.01 | 10  | μA   |
| PSRR                      | Power supply rejection ratio | Zero scale,                                                             |                       | See Note 2 | –65 |      |     | dB   |
|                           |                              | Full scale,                                                             |                       | See Note 3 | –65 |      |     |      |

NOTES: 2. Power supply rejection ratio at zero scale is measured by varying AV<sub>DD</sub> and is given by:

$$\text{PSRR} = 20 \log [(E_{\text{ZS}}(\text{AV}_{\text{DDmax}}) - E_{\text{ZS}}(\text{AV}_{\text{DDmin}}))/\text{AV}_{\text{DDmax}}]$$

3. Power supply rejection ratio at full scale is measured by varying AV<sub>DD</sub> and is given by:

$$\text{PSRR} = 20 \log [(E_{\text{G}}(\text{AV}_{\text{DDmax}}) - E_{\text{G}}(\text{AV}_{\text{DDmin}}))/\text{AV}_{\text{DDmax}}]$$

## static DAC specifications

| PARAMETER                                       |                                               | TEST CONDITIONS                              |            | MIN   | TYP | MAX  | UNIT            |
|-------------------------------------------------|-----------------------------------------------|----------------------------------------------|------------|-------|-----|------|-----------------|
| Resolution                                      |                                               | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V  |            | 12    |     |      | bits            |
| Integral nonlinearity (INL), end point adjusted |                                               | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V, | See Note 4 | ±1.5  |     | ±4   | LSB             |
| Differential nonlinearity (DNL)                 |                                               | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V, | See Note 5 | ±0.4  |     | ±1   | LSB             |
| E <sub>ZS</sub>                                 | Zero-scale error (offset error at zero scale) | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V, | See Note 6 | ±3    |     | ±20  | mV              |
| Zero-scale-error temperature coefficient        |                                               | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V, | See Note 7 | 3     |     |      | ppm/°C          |
| E <sub>G</sub>                                  | Gain error                                    | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V, | See Note 8 | ±0.25 |     | ±0.5 | % of FS voltage |
| Gain error temperature coefficient              |                                               | V <sub>ref</sub> (REFIN) = 2.048 V, 1.024 V, | See Note 9 | 1     |     |      | ppm/°C          |

NOTES: 4. The relative accuracy or integral nonlinearity (INL) sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale excluding the effects of zero code and full-scale errors.

5. The differential nonlinearity (DNL) sometimes referred to as differential error, is the difference between the measured and ideal 1 LSB amplitude change of any two adjacent codes. Monotonic means the output voltage changes in the same direction (or remains constant) as a change in the digital input code.

6. Zero-scale error is the deviation from zero voltage output when the digital input code is zero.

7. Zero-scale-error temperature coefficient is given by:  $E_{\text{ZS}} \text{ TC} = [E_{\text{ZS}}(T_{\text{max}}) - E_{\text{ZS}}(T_{\text{min}})]/V_{\text{ref}} \times 10^6/(T_{\text{max}} - T_{\text{min}})$ .

8. Gain error is the deviation from the ideal output (V<sub>ref</sub> – 1 LSB) with an output load of 10 kΩ excluding the effects of the zero-error.

9. Gain temperature coefficient is given by:  $E_{\text{G}} \text{ TC} = [E_{\text{G}}(T_{\text{max}}) - E_{\text{G}}(T_{\text{min}})]/V_{\text{ref}} \times 10^6/(T_{\text{max}} - T_{\text{min}})$ .

## output specifications

| PARAMETER                       |                                     | TEST CONDITIONS                                        |                        | MIN  | TYP                   | MAX  | UNIT            |
|---------------------------------|-------------------------------------|--------------------------------------------------------|------------------------|------|-----------------------|------|-----------------|
| V <sub>O</sub>                  | Output voltage                      | R <sub>L</sub> = 10 kΩ                                 |                        | 0    | AV <sub>DD</sub> –0.4 |      | V               |
| Output load regulation accuracy |                                     | V <sub>O</sub> (OUT) = 4.096 V, R <sub>L</sub> = 2 kΩ, |                        | 0.1  |                       | 0.29 | % of FS voltage |
| I <sub>OSC</sub> (source)       | Output short circuit source current | V <sub>O</sub> (OUT) = 0 V, input all 1s               | AV <sub>DD</sub> = 5 V | –100 |                       |      | mA              |
|                                 |                                     |                                                        | AV <sub>DD</sub> = 3 V | –25  |                       |      |                 |
| I <sub>OSC</sub> (sink)         | Output short circuit sink current   | R <sub>L</sub> = 100 Ω, input all 1s                   | AV <sub>DD</sub> = 5 V | –10  |                       |      | mA              |
|                                 |                                     |                                                        | AV <sub>DD</sub> = 3 V | –10  |                       |      |                 |

# TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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**electrical characteristics over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)**

### reference input (REFIN)

| PARAMETER                                | TEST CONDITIONS                                               | MIN | TYP       | MAX                   | UNIT |
|------------------------------------------|---------------------------------------------------------------|-----|-----------|-----------------------|------|
| V <sub>ref</sub> Input voltage reference | See Note 10                                                   | 0   |           | AV <sub>DD</sub> –1.5 | V    |
| R <sub>i</sub> Input resistance          |                                                               |     | 10        |                       | MΩ   |
| C <sub>i</sub> Input capacitance         |                                                               |     | 5         |                       | pF   |
| Reference input bandwidth                | REF = 0.2 V <sub>pp</sub> + 1.024 V dc                        |     | Fast mode | 1.6                   | MHz  |
|                                          |                                                               |     | Slow mode | 1                     | MHz  |
| Reference feed through                   | REF = 1 V <sub>pp</sub> at 1 kHz + 1.024 V dc,<br>See Note 10 |     | –60       |                       | dB   |

NOTES: 10. Reference feedthrough is measured at the DAC output with an input code = 0x000.

### digital inputs

| PARAMETER                                        | TEST CONDITIONS                   | MIN | TYP | MAX | UNIT |
|--------------------------------------------------|-----------------------------------|-----|-----|-----|------|
| I <sub>IH</sub> High-level digital input current | V <sub>I</sub> = DV <sub>DD</sub> |     |     | 1   | μA   |
| I <sub>IL</sub> Low-level digital input current  | V <sub>I</sub> = 0 V              | –1  |     |     | μA   |
| C <sub>i</sub> Input capacitance                 |                                   |     | 8   |     | pF   |

**operating characteristics over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)**

### analog output dynamic performance

| PARAMETER                                              | TEST CONDITIONS                                                                                        | MIN | TYP  | MAX | UNIT |
|--------------------------------------------------------|--------------------------------------------------------------------------------------------------------|-----|------|-----|------|
| t <sub>s</sub> (FS) Output settling time, full scale   | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF, See Note 11                                           |     | Fast | 1   | μs   |
|                                                        |                                                                                                        |     | Slow | 3.5 |      |
| t <sub>s</sub> (CC) Output settling time, code-to-code | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF, See Note 12                                           |     | Fast | 0.5 | μs   |
|                                                        |                                                                                                        |     | Slow | 1   |      |
| SR Slew rate                                           | R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF, See Note 13                                           |     | Fast | 8   | V/μs |
|                                                        |                                                                                                        |     | Slow | 1.5 |      |
| Glitch energy                                          | Code-to-code transition                                                                                |     | 1    |     | nV–s |
| S/N Signal-to-noise                                    | f <sub>s</sub> = 480 KSPS, f <sub>out</sub> = 1 kHz,<br>R <sub>L</sub> = 10 k, C <sub>L</sub> = 100 pF | 65  | 78   |     | dB   |
| S/(N+D) Signal-to-noise + distortion                   |                                                                                                        | 58  | 69   |     |      |
| THD Total harmonic distortion                          |                                                                                                        | –68 | –60  |     |      |
| Spurious free dynamic range                            |                                                                                                        | 60  | 72   |     |      |

NOTES: 11. Settling time is the time for the output signal to remain within ±0.5 LSB of the final measured value for a digital input code change of 0x020 to 0x3FF or 0x3FF to 0x020.

12. Settling time is the time for the output signal to remain within ± 0.5 LSB of the final measured value for a digital input code change of one count. The max time applies to code changes near zero scale or full scale.

13. Slew rate determines the time it takes for a change of the DAC output from 10% to 90% full-scale voltage.



# TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### timing requirements

#### digital inputs

|                 |                                                                        | MIN | NOM | MAX | UNIT    |
|-----------------|------------------------------------------------------------------------|-----|-----|-----|---------|
| $t_{su}(D)$     | Setup time, data ready before positive $\overline{WE}$ edge            | 9   |     |     | ns      |
| $t_{su}(CS-WE)$ | Setup time, $\overline{CS}$ low before positive $\overline{WE}$ edge   | 13  |     |     | ns      |
| $t_{su}(A)$     | Setup time, address bits A0, A1                                        | 17  |     |     | ns      |
| $t_h(D)$        | Hold time, data held after positive $\overline{WE}$ edge               | 0   |     |     | ns      |
| $t_{su}(WE-LD)$ | Setup time, positive $\overline{WE}$ edge before $\overline{LDAC}$ low | 0   |     |     | ns      |
| $t_w(WE)$       | Pulse duration, $\overline{WE}$ high                                   | 25  |     |     | ns      |
| $t_w(LD)$       | Pulse duration, $\overline{LDAC}$ low                                  | 25  |     |     | $\mu$ s |

### PARAMETER MEASUREMENT INFORMATION

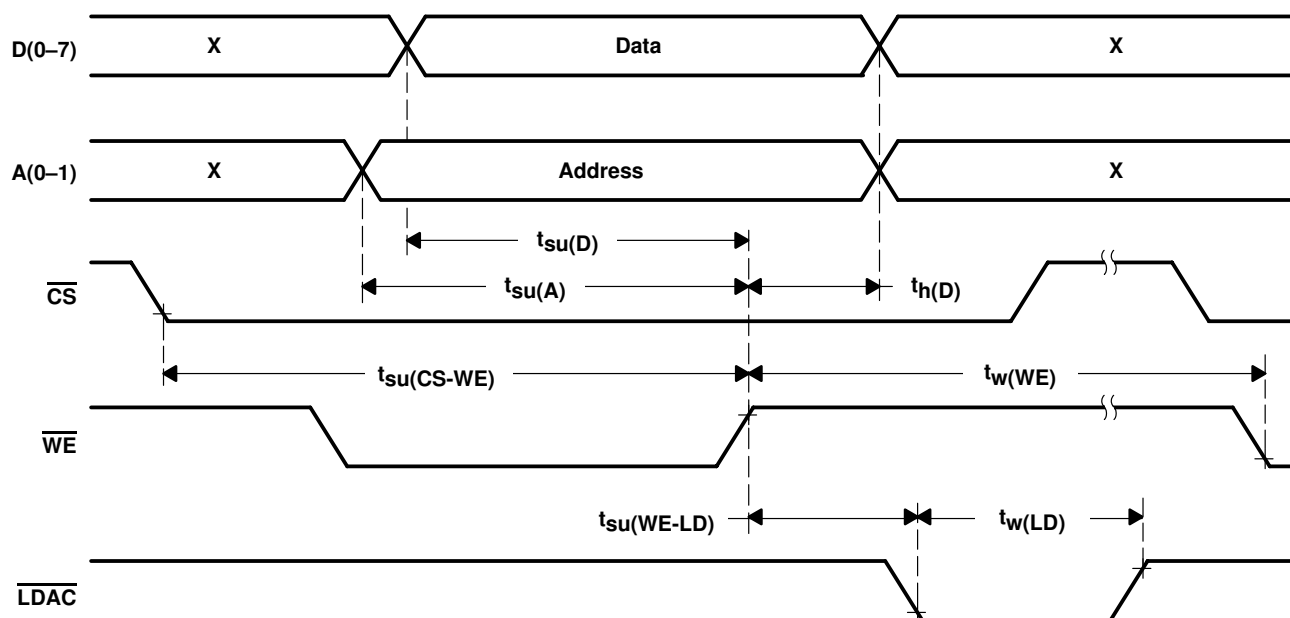


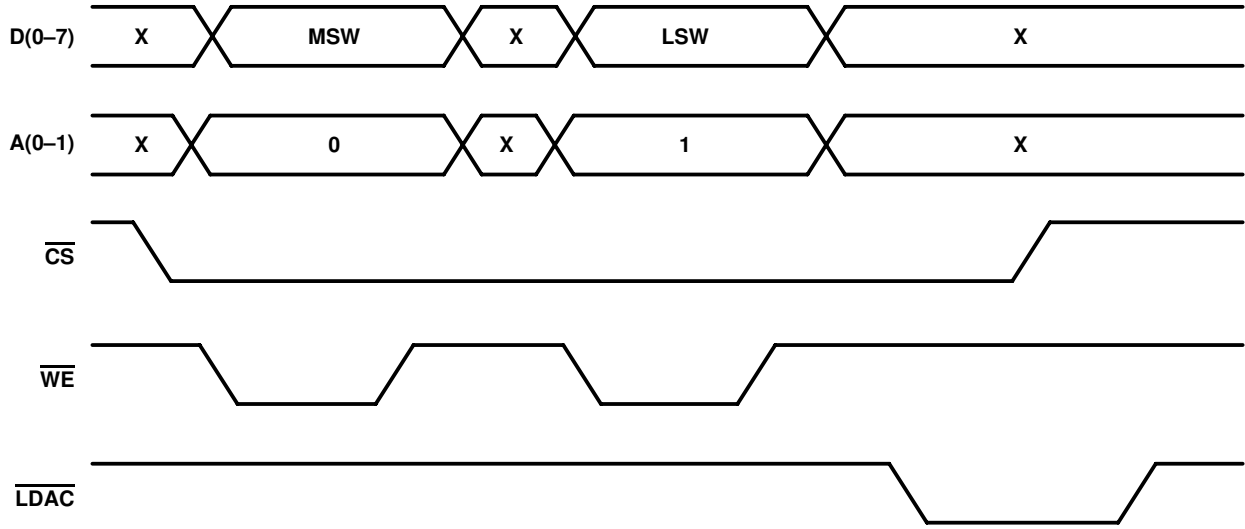
Figure 1. Timing Diagram

TLV5613

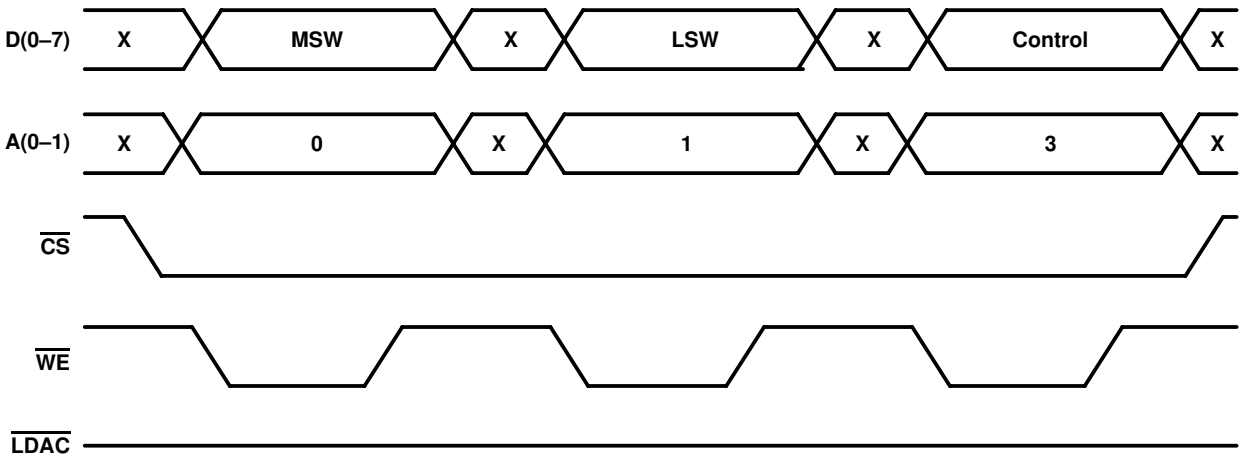
## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### PARAMETER MEASUREMENT INFORMATION



**Figure 2. Example of a Complete Write Cycle Using  $\overline{\text{LDAC}}$  to Update the DAC**



**Figure 3. Example of a Complete Write Cycle Using the Control Word to Update the DAC**

# TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### TYPICAL CHARACTERISTICS

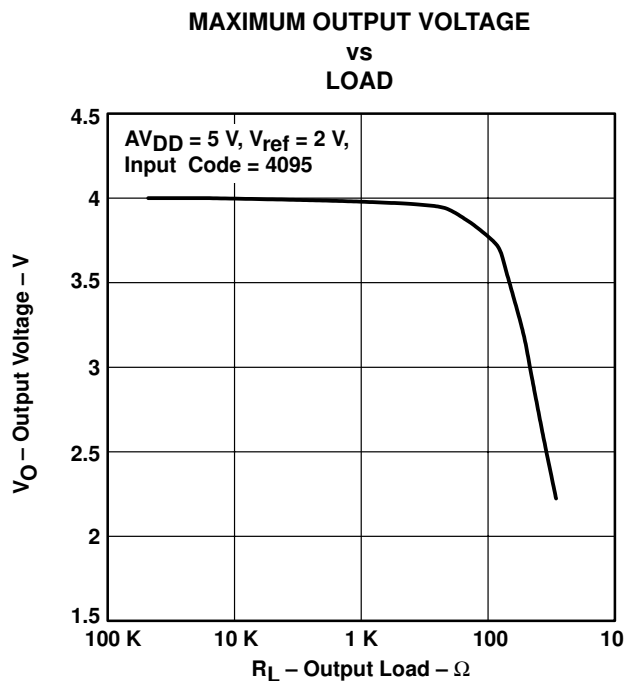


Figure 4

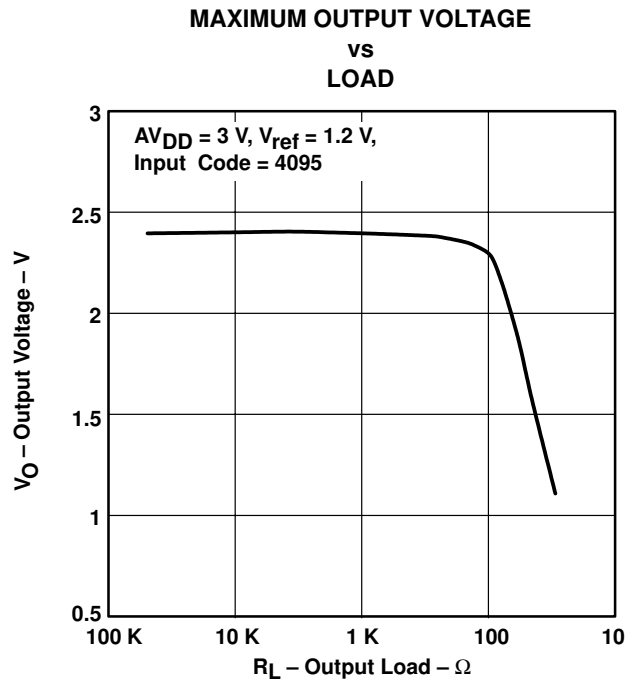


Figure 5

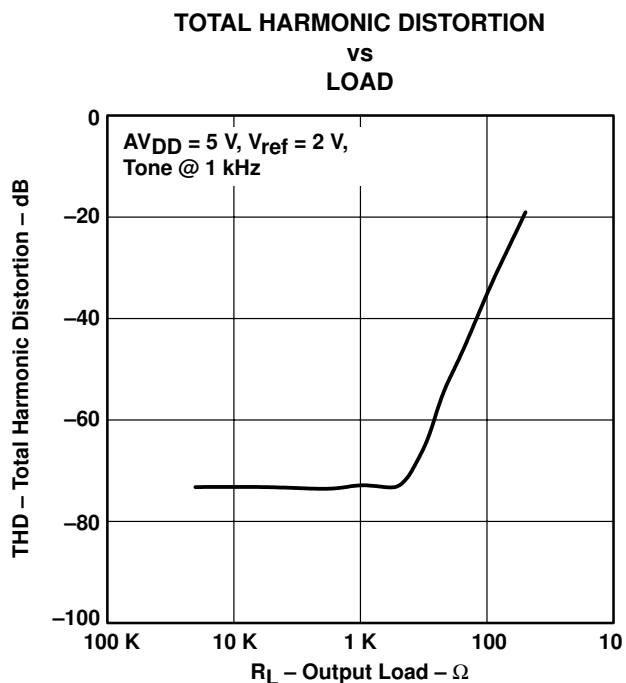


Figure 6

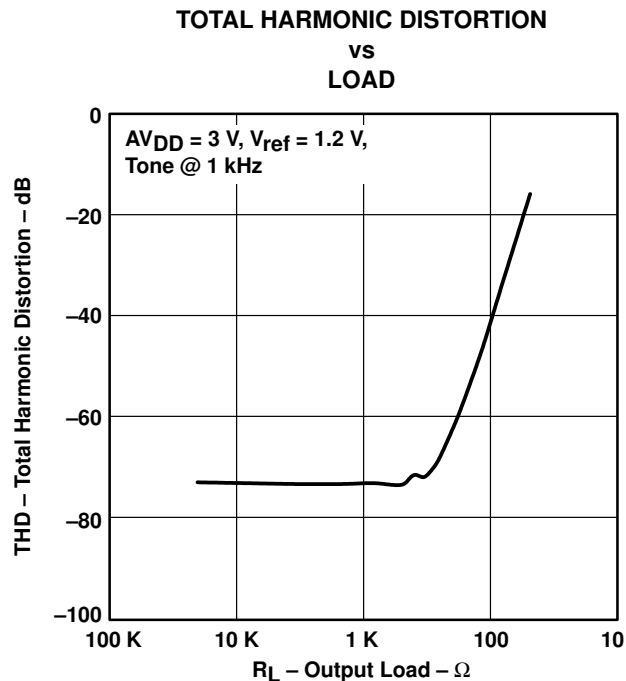


Figure 7

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# 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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## TYPICAL CHARACTERISTICS

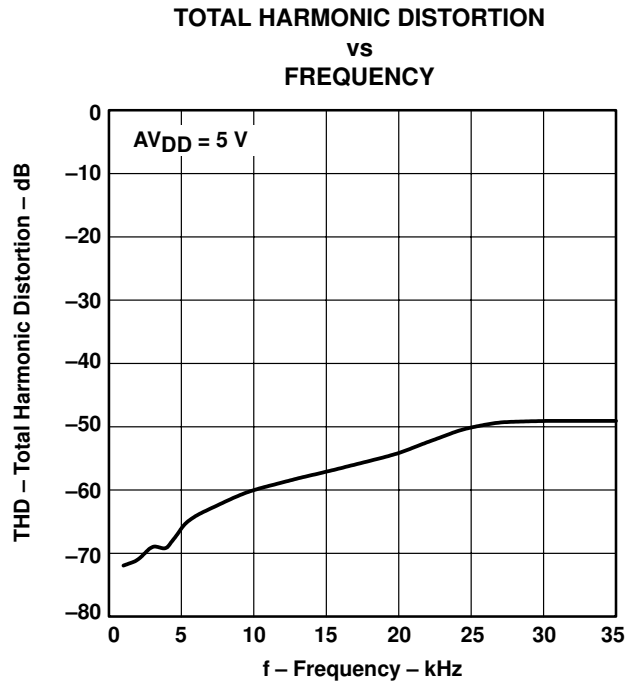


Figure 8

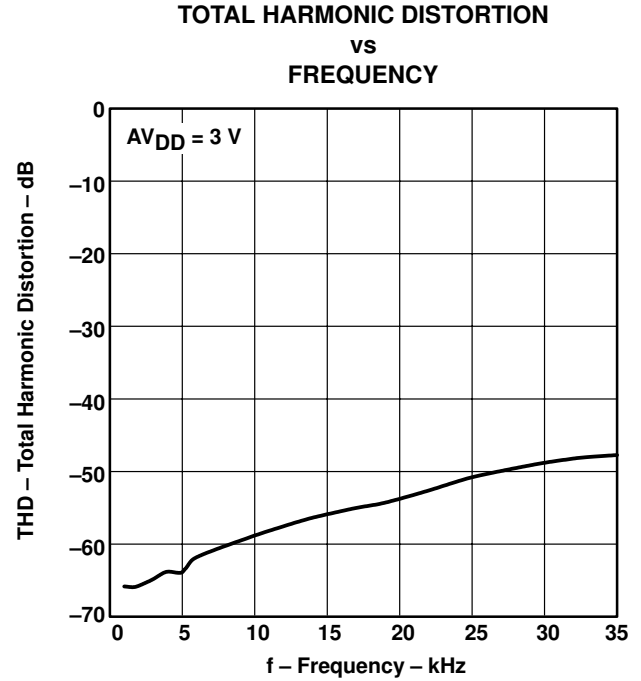


Figure 9

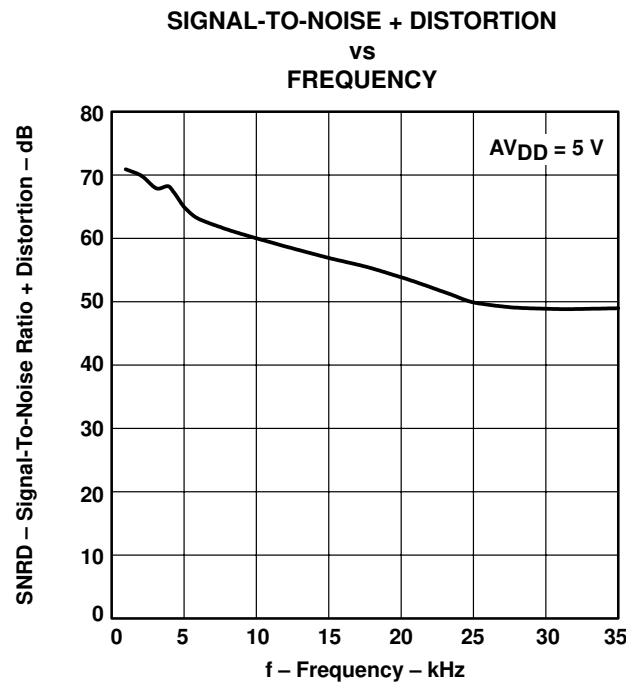


Figure 10

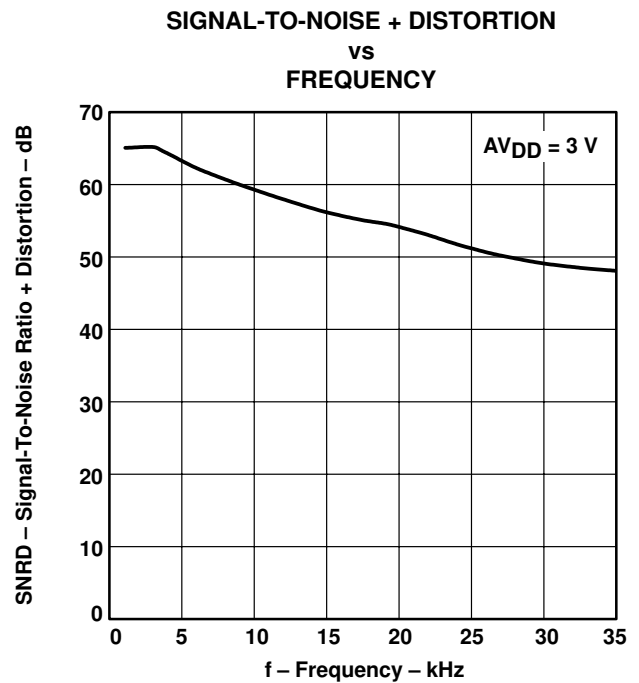
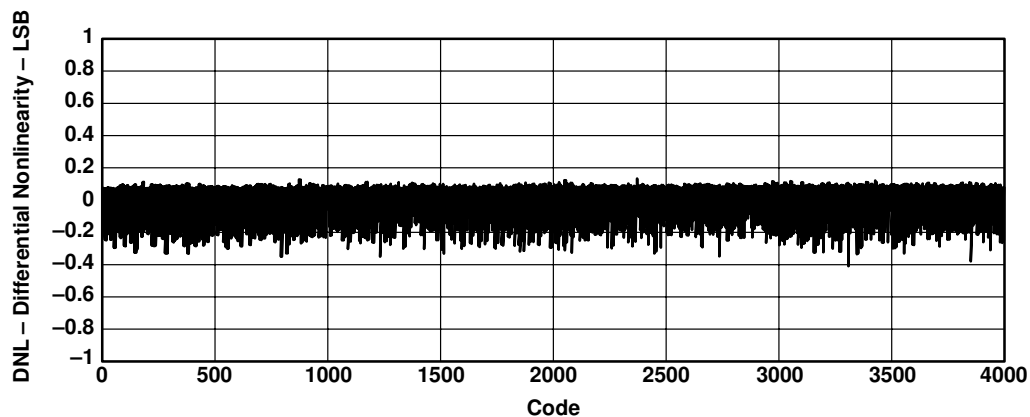
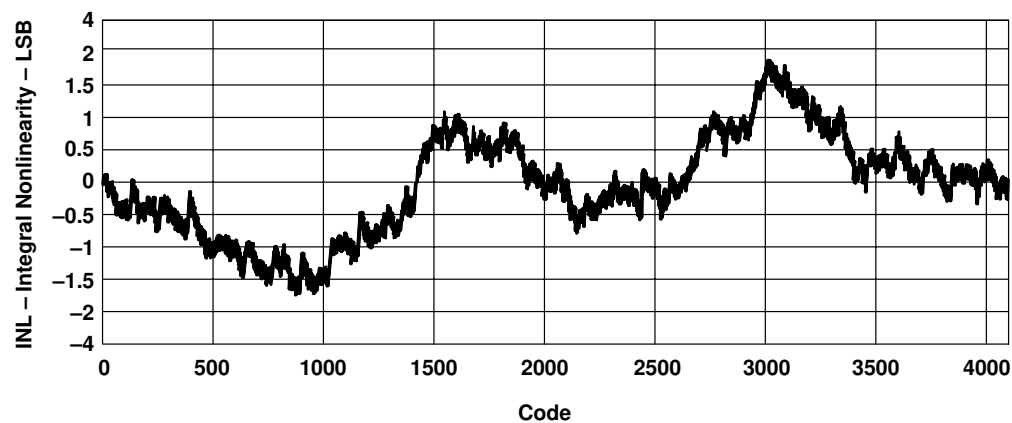


Figure 11

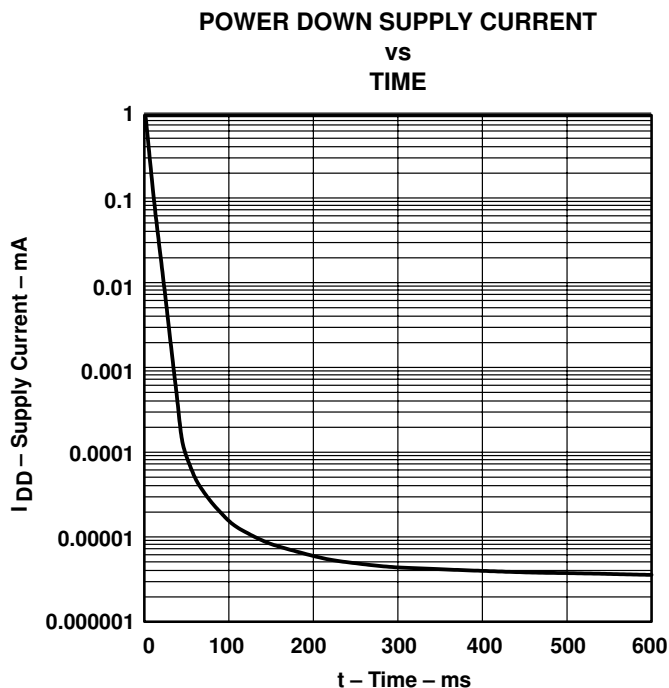
**TYPICAL CHARACTERISTICS****Figure 12. Differential Nonlinearity****Figure 13. Integral Nonlinearity**

# TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### TYPICAL CHARACTERISTICS



### APPLICATION INFORMATION

#### general function

The TLV5613 is a 12-bit, single supply DAC, based on a resistor string architecture. It consists of a parallel interface, speed and power down control logic, a resistor string and a rail-to-rail output buffer. The output voltage (full scale determined by reference) is given by:

$$2 \text{ REF } \frac{\text{CODE}}{0x1000} [\text{V}]$$

Where REF is the reference voltage and CODE is the digital input value, range 0x000 to 0xFFF. A power on reset initially puts the internal latches to a defined state (all bits zero).

#### parallel interface

The device latches data on the positive edge of  $\overline{\text{WE}}$ . It must be enabled with  $\overline{\text{CS}}$  low. Whether the data is written to one of the DAC holding latches (MSW, LSW) or the control register, depends on the address bits A1 and A0.  $\overline{\text{LDAC}}$  low updates the DAC with the value in the holding latch.  $\overline{\text{LDAC}}$  is an asynchronous input and can be held low, if a separate update is not necessary. Two more asynchronous inputs, SPD and  $\overline{\text{PWD}}$  control the settling times and the power down mode:

|                           |               |                      |                |
|---------------------------|---------------|----------------------|----------------|
| SPD:                      | Speed control | 1 → fast mode        | 0 → slow mode  |
| $\overline{\text{PWD}}$ : | Power control | 1 → normal operation | 0 → power down |



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## APPLICATION INFORMATION

It is also possible to program the different modes (fast, slow, power down) and the DAC update latch using the control register. The following tables list the possible combination of the control signals and control bits.

| PIN | BIT | MODE |
|-----|-----|------|
| SPD | SPD |      |
| 0   | 0   | Slow |
| 0   | 1   | Fast |
| 1   | 0   | Fast |
| 1   | 1   | Fast |

| PIN                     | BIT | POWER  |
|-------------------------|-----|--------|
| $\overline{\text{PWD}}$ | PWD |        |
| 0                       | 0   | Down   |
| 0                       | 1   | Down   |
| 1                       | 0   | Normal |
| 1                       | 1   | Down   |

| PIN                      | BIT   | LATCH       |
|--------------------------|-------|-------------|
| $\overline{\text{LDAC}}$ | RLDAC |             |
| 0                        | 0     | Transparent |
| 0                        | 1     | Transparent |
| 1                        | 0     | Hold        |
| 1                        | 1     | Transparent |

## data format

The TLV5613 writes data either to one of the DAC holding latches or to the control register depending on the address bits A1 and A0.

### ADDRESS BITS

| A1 | A0 | REGISTER        |
|----|----|-----------------|
| 0  | 0  | DAC LSW holding |
| 0  | 1  | DAC MSW holding |
| 1  | 0  | Reserved        |
| 1  | 1  | Control         |

| D7 | D6 | D5 | D4 | D3 | D2    | D1  | D0  |
|----|----|----|----|----|-------|-----|-----|
| X  | X  | X  | X  | X  | RLDAC | PWD | SPD |

X: Don't care

SPD: Speed control bit

1 → fast mode

0 → slow mode

PWD: Power control bit

1 → power down

0 → normal operation

RLDAC: Load DAC latch

1 → latch transparent

0 → DAC latch controlled by  $\overline{\text{LDAC}}$  pin

## APPLICATION INFORMATION

### layout considerations

To achieve the best performance, it is recommended to have separate power planes for GND,  $AV_{DD}$ , and  $DV_{DD}$ . Figure 15 shows how to lay out the power planes for the TLV5613. As a general rule, digital and analog signals should be separated as wide as possible. To avoid crosstalk, analog and digital traces must not be routed in parallel. The two positive power planes ( $AV_{DD}$  and  $DV_{DD}$ ) should be connected together at one point with a ferrite bead.

A 100-nF ceramic low series inductance capacitor between  $DV_{DD}$  and GND and a 1- $\mu$ F tantalum capacitor between  $AV_{DD}$  and GND as close as possible to the supply pins are recommended for optimal performance.

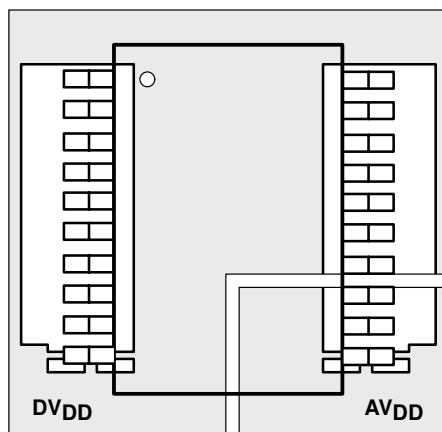


Figure 15. TLV5613 Board Layout

### linearity, offset, and gain error using single end supplies

When an amplifier is operated from a single supply, the voltage offset can still be either positive or negative. With a positive offset, the output voltage changes on the first code change. With a negative offset the output voltage may not change with the first code depending on the magnitude of the offset voltage.

The output amplifier attempts to drive the output to a negative voltage. However, because the most negative supply rail is ground, the output cannot drive below ground and clamps the output at 0 V.

The output voltage remains at zero until the input code value produces a sufficient positive output voltage to overcome the negative offset voltage, resulting in the transfer function shown in Figure 16.

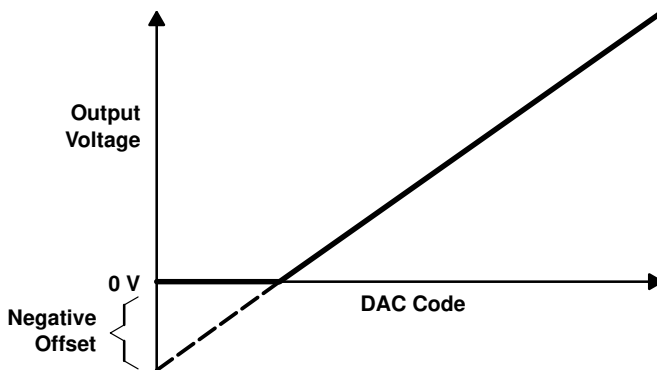


Figure 16. Effect of Negative Offset (Single Supply)

## APPLICATION INFORMATION

This offset error, not the linearity error, produces this breakpoint. The transfer function would have followed the dotted line if the output buffer could drive below the ground rail.

For a DAC, linearity is measured between zero input code (all inputs 0) and full scale code (all inputs 1) after offset and full scale are adjusted out or accounted for in some way. However, single supply operation does not allow for adjustment when the offset is negative due to the breakpoint in the transfer function. So the linearity is measured between full scale code and the lowest code that produces a positive output voltage.

### TLV5613 interfaced to an Intel MCS<sup>®</sup>251 controller

The circuit in Figure 17 shows how to interface the TLV5613 to an Intel MCS<sup>®</sup>251 microcontroller. The address bus and the data bus of the controller are multiplexed on port 0 (non page mode) to save port pins. To separate the address bits and the data bits, the controller provides a dedicated signal, address latch enable (ALE), which is connected to a latch at port 0.

An address decoder is required to generate the chip select signal for the TLV5613. In this example, a simple 3-to-8 decoder (74AC138) is used for the interface as shown in Figure 17. The DAC is memory mapped at addresses 0x8000/1/2/3 within the data memory address space and mirrored every 32 address locations (0x8020/1/2/3, 0x8040/1/2/3, etc.). In a typical microcontroller system, programmable logic should be used to generate the chip select signals for the entire system.

The data pins and the  $\overline{WE}$  pin of the TLV5613 can be connected directly to the multiplexed address and data bus and the  $\overline{WR}$  signal of the controller.

$\overline{LDAC}$  is held high so that the output voltage is updated using the RLDAC bit in the control register. Hardware power down mode is deactivated permanently by pulling PWD to  $DV_{DD}$ .

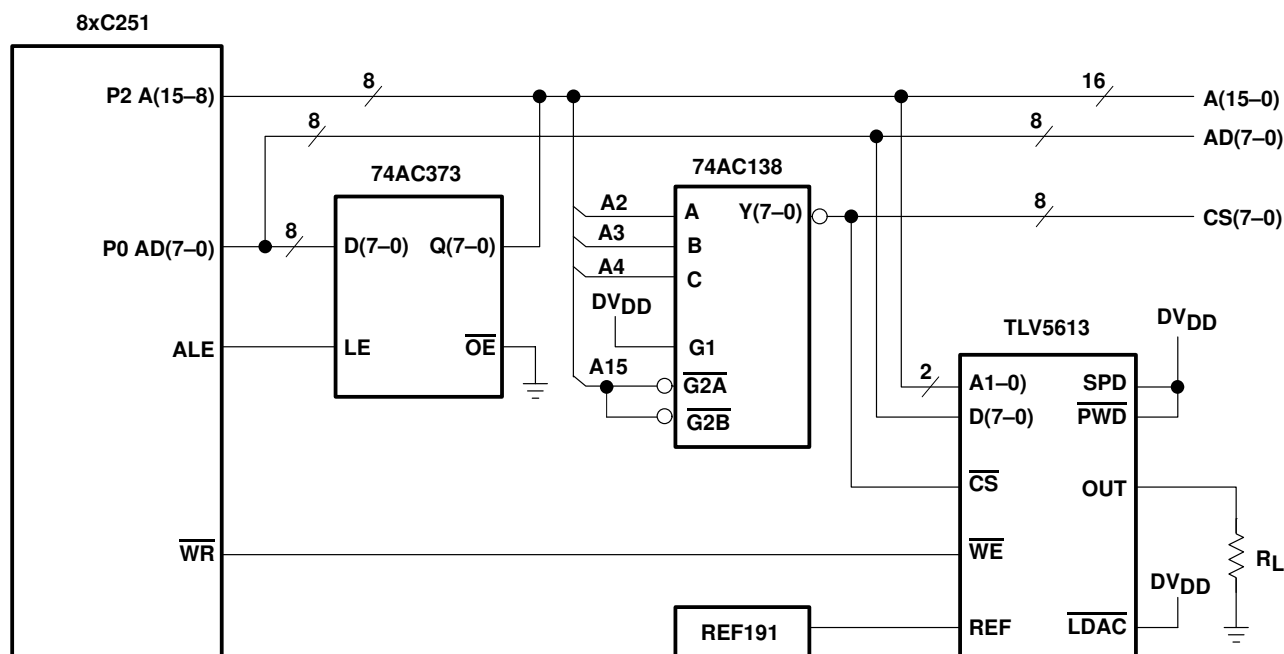


Figure 17. TLV5613 Interfaced to an Intel MCS<sup>®</sup>251 Controller

TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### APPLICATION INFORMATION

#### software

In the following example, the code generates a waveform at 500 KSPS with 500 samples stored in a table within the program memory space of the microcontroller. The period of the waveform is 1 ms.

The waveform data is located in the program memory space from address 01000h to address 013E8h ( $2 \times 500 = 1000 = 03E8h$ ) beginning with the MSW of the first 16-bit word (the 4 MSBs are ignored), followed by the LSW. Two bytes are required for each DAC word (the table is not shown in the code example).

The program consists of two parts:

- A main routine, which is executed after reset and which initializes the timer and the interrupt system of the microcontroller.
- An interrupt service routine, which reads a new value from the waveform table and writes it to the DAC.

This example uses timer 0 in mode 3 (8-bit timer with auto reload). The clock of the timer is derived from the system clock and has a frequency of  $f_{OSC}/12$ . The timer overrun frequency  $f_{tim}$  is given by the following equation:

$$f_{tim} = \frac{f_{OSC}}{12(256 - \text{Reload})} \text{ and the reload value is given by } \text{Reload} = 256 - \frac{f_{OSC}}{12 f_{tim}}$$

To get a timer overrun frequency of 500 kHz at a system clock of 24 MHz, the reload value is:

$$\text{Reload} = 256 - \frac{24}{12 \times 0.5} = 256 - 4 = 252 = 0FCh$$

With this value, the timer generates an interrupt every 2  $\mu$ s. The corresponding service routine `T0_isr` reads a sample from program memory and writes it to the DAC. First, it disables the update of the DAC output by clearing the RLDAC bit in the control register. Then it reads the MSW and the LSW from the waveform table and stores it in the MSW and LSW register of the TLV5613. The write cycle is completed by setting the RLDAC bit, which updates the DAC output. At the end of the interrupt service routine, the pointer to the waveform samples is increased and is checked to determine if it has reached the end of the table. If the pointer has reached the end of the table, the pointer is set to the start address of the table.

# 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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## APPLICATION INFORMATION

```

;*****
;* Title   : Waveform generation with TLV5613          *
;* Version: 1.0                                         *
;* MCU     : Intel MCS@251, MCS@51                    *
;* © 1998 Texas Instruments Inc.                       *
;*****

TABLE_START EQU 01000h      ;start address of waveform data
TABLE_END_H EQU 013h        ;high byte - end address of waveform data
TABLE_END_L EQU 0E8h        ;low byte - end address of waveform data
RELOAD      EQU 0FCh        ;timer reload value

                ORG 00000h    ;entry point
                JMP main      ;jump to main program
                ORG 0000bh    ;timer0 (T0) interrupt vector
                JMP T0_isr     ;jump to T0 interrupt service routine

;-----
;main: setup timer and interrupt, loop forever
;-----

main:          CLR A
               MOV A, IE0      ;disable all interrupts
               CLR TCON.4      ;stop T0
               MOV A, #002h
               MOV TMOD, A      ;set T0 to auto reload mode
               MOV A, #RELOAD
               MOV TH0, A       ;set T0 reload value
               MOV TL0, A       ;set T0 start value
               MOV P2, #080h    ;set A15 of address bus to select DAC

               MOV DPTR, #TABLE_START ;set data pointer to start of wave form data

               SETB IE0.1      ;enable T0 interrupt
               SETB IE0.7      ;enable interrupts
               SETB TCON.4      ;start T0
idle_loop:     SJMP idle_loop   ;loop forever

```

TLV5613

## 2.7 V TO 5.5 V 12-BIT PARALLEL DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

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### APPLICATION INFORMATION

```
;-----  
;T0_isr: will be called on every timer interrupt.  
;fetches a new 16-bit value from program memory space and writes it  
;to the DAC. If end of table is reached, sets DPTR to table start addr.  
;-----  
T0_isr:      MOV R0, #003h          ;select DAC control register  
             MOV A, #001h          ;RLDAC=0, PWD=0, SPD=1  
                                     ;no DAC update, normal operation, fast mode  
             MOVX @R0, A           ;write Accu to DAC control register  
  
             MOV R0, #001h          ;select DAC MSW register  
             CLR A  
             MOVC A, @A+DPTR        ;get MSW from code memory  
             MOVX @R0, A           ;write Accu to DAC MSW register  
  
             INC DPTR              ;set DPTR to LSW data  
  
             MOV R0, #000h          ;select DAC LSW register  
             CLR A  
             MOVC A, @A+DPTR        ;get LSW from code memory  
             MOVX @R0, A           ;write Accu to DAC LSW register  
  
             MOV R0, #003h          ;select DAC control register (to update DAC)  
             MOV A, #005h          ;DAC update, normal operation, fast mode  
             MOVX @R0, A           ;write Accu to DAC control register  
  
             INC DPTR              ;set DPTR to next MSW  
                                     ;test end of table  
  
             MOV A, DPL  
             CJNE A, #TABLE_END_L, T0_isr_end  
             MOV A, DPH  
             CJNE A, #TABLE_END_H, T0_isr_end  
             MOV DPTR, #TABLE_START ;end of table reached -> start again  
T0_isr_end: RETI  
  
END
```



**APPLICATION INFORMATION****definitions of specifications and terminology****integral nonlinearity (INL)**

The relative accuracy or integral nonlinearity (INL), sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale excluding the effects of zero code and full-scale errors.

**differential nonlinearity (DNL)**

The differential nonlinearity (DNL), sometimes referred to as differential error, is the difference between the measured and ideal 1 LSB amplitude change of any two adjacent codes. Monotonic means the output voltage changes in the same direction (or remains constant) as a change in the digital input code.

**zero-scale error ( $E_{ZS}$ )**

Zero-scale error is defined as the deviation of the output from 0 V at a digital input value of 0.

**gain error ( $E_G$ )**

Gain error is the error in slope of the DAC transfer function.

**signal-to-noise ratio + distortion (SINAD)**

Signal-to-noise ratio + distortion is the ratio of the rms value of the output signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc. The value for SINAD is expressed in decibels.

**spurious free dynamic range (SFDR)**

Spurious free dynamic range is the difference between the rms value of the output signal and the rms value of the spurious signal within a specified bandwidth. The value for SFDR is expressed in decibels.

**total harmonic distortion (THD)**

Total harmonic distortion is the ratio of the rms sum of the first six harmonic components to the rms value of the fundamental signal and is expressed in decibels.

## PACKAGING INFORMATION

| Orderable part number      | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|----------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TLV5613CDW</a> | Active        | Production           | SOIC (DW)   20  | 25   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | 0 to 70      | TLV5613C            |
| TLV5613CDW.A               | Active        | Production           | SOIC (DW)   20  | 25   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | 0 to 70      | TLV5613C            |
| <a href="#">TLV5613CPW</a> | Active        | Production           | TSSOP (PW)   20 | 70   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | 0 to 70      | TV5613              |
| TLV5613CPW.A               | Active        | Production           | TSSOP (PW)   20 | 70   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | 0 to 70      | TV5613              |
| <a href="#">TLV5613IDW</a> | Active        | Production           | SOIC (DW)   20  | 25   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | TLV5613I            |
| TLV5613IDW.A               | Active        | Production           | SOIC (DW)   20  | 25   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | TLV5613I            |
| <a href="#">TLV5613IPW</a> | Active        | Production           | TSSOP (PW)   20 | 70   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | TY5613              |
| TLV5613IPW.A               | Active        | Production           | TSSOP (PW)   20 | 70   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | TY5613              |

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

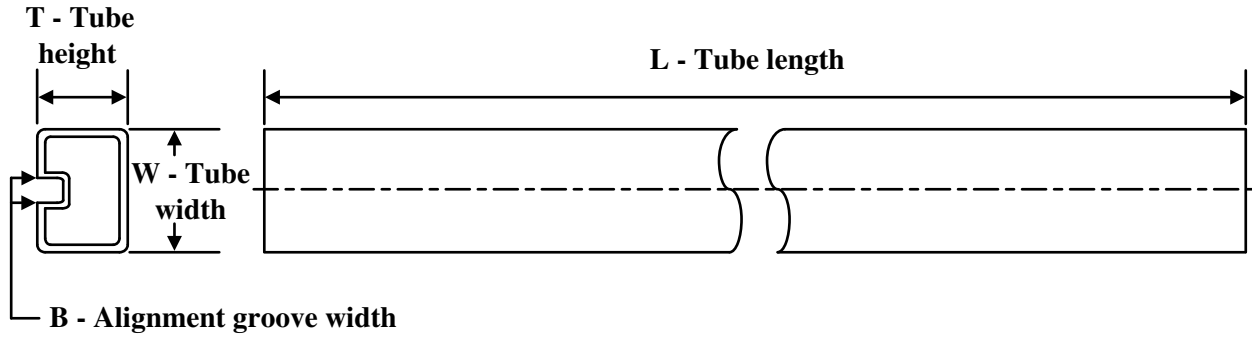
(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TUBE



\*All dimensions are nominal

| Device       | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|--------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| TLV5613CDW   | DW           | SOIC         | 20   | 25  | 506.98 | 12.7   | 4826   | 6.6    |
| TLV5613CDW.A | DW           | SOIC         | 20   | 25  | 506.98 | 12.7   | 4826   | 6.6    |
| TLV5613CPW   | PW           | TSSOP        | 20   | 70  | 530    | 10.2   | 3600   | 3.5    |
| TLV5613CPW.A | PW           | TSSOP        | 20   | 70  | 530    | 10.2   | 3600   | 3.5    |
| TLV5613IDW   | DW           | SOIC         | 20   | 25  | 506.98 | 12.7   | 4826   | 6.6    |
| TLV5613IDW.A | DW           | SOIC         | 20   | 25  | 506.98 | 12.7   | 4826   | 6.6    |
| TLV5613IPW   | PW           | TSSOP        | 20   | 70  | 530    | 10.2   | 3600   | 3.5    |
| TLV5613IPW.A | PW           | TSSOP        | 20   | 70  | 530    | 10.2   | 3600   | 3.5    |

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